HVC317B

Variable Capacitance Diode for tuner

HITACHI

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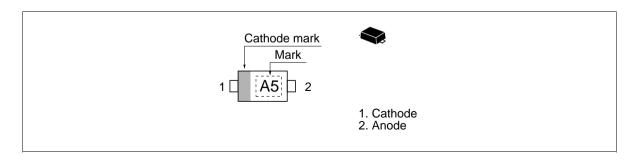
Features

- High capacitance ratio. (n =13.0 min)
- Ultra small Flat Package (UFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVC317B	A5	UFP

Outline





HVC317B

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V_R	35	V
Junction temperature	Тј	125	°C
Storage temperature	Tstg	-55 to +125	°C

Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _{R1}	_	_	10	nA	$V_R = 30V$
	I _{R2}	_	_	100		V _R = 30V, Ta = 60 °C
Capacitance	C ₁	9.00	_	11.5	pF	V _R = 1V, f = 1 MHz
	C ₂₅	0.60	_	0.80	_	V _R = 25V, f = 1 MHz
Capacitance ratio	n	13.0	_	_	_	C ₁ / C ₂₅
Series resistance	r_s	_	_	1.6	Ω	V _R = 5V, f = 470 MHz
Matching error	ΔC/C*1	_	_	6.0	%	V _R = 1 to 25V, f = 1 MHz

C.C system (Continuous Connected taping system) enable to make any 10 pcs of ΔC/C continuous in a reel , expect extention to another group.
Calculate Matching Error,

$$\Delta \text{C/C=} \quad \frac{\text{(Cmax-Cmin)}}{\text{Cmin}} \quad \text{x 100 (\%)}$$

Main Characteristic

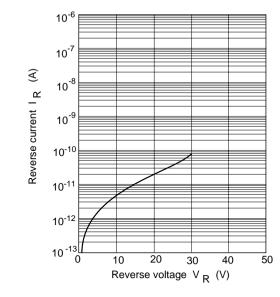


Fig.1 Reverse current Vs. Reverse voltage

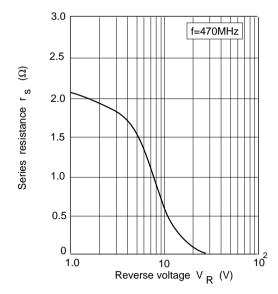


Fig.3 Series resistance Vs. Reverse voltage

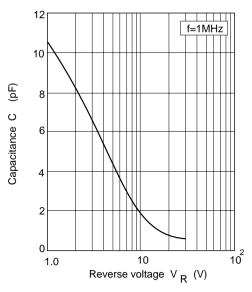


Fig.2 Capacitance Vs. Reverse voltage

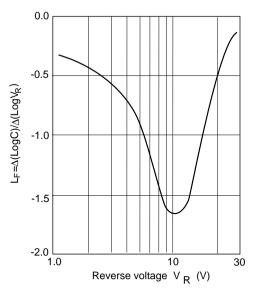
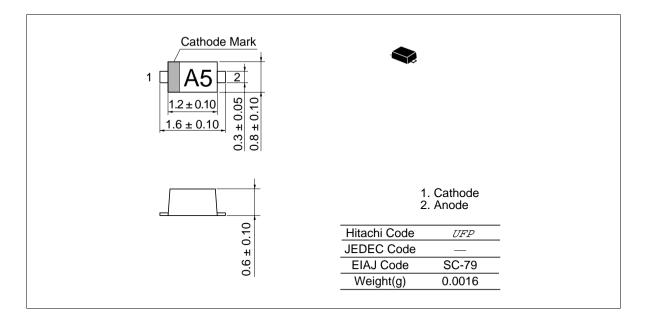


Fig.4 Linearity factor Vs. Reverse voltage

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Package Dimensions

Unit: mm



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